

## CPV Dense Array Solar Cells C3MJ Third Generation CPV Technology

### Product Description

Typical Aperture Area Efficiency 38.5%  
Recommended operating temperature <math><110^{\circ}\text{C}</math>

### Epitaxial Structure

Triple junction solar cell on Germanium substrate  
GaInP (1.88 eV) / GaInAs (1.41 eV) / Ge (0.67 eV)

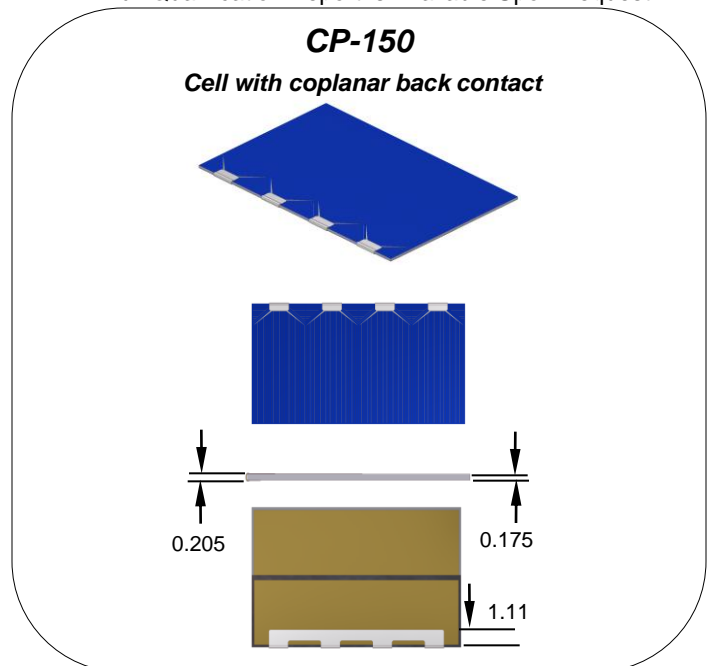
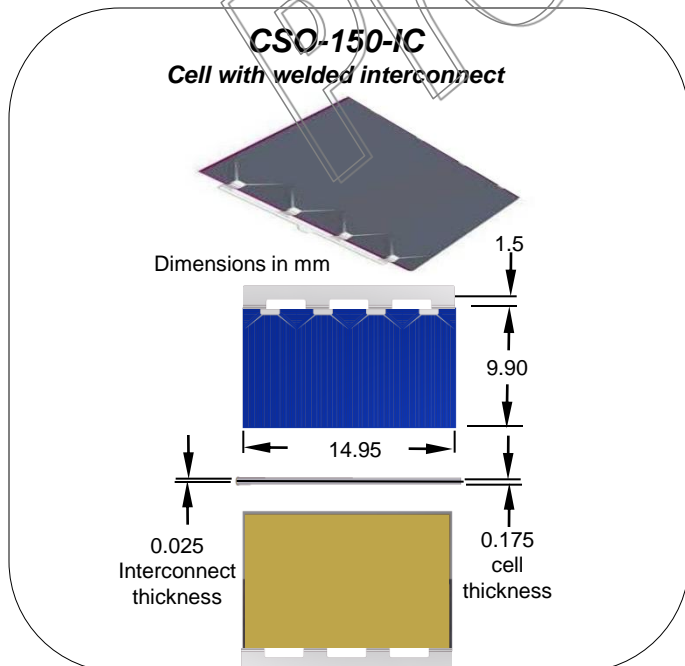
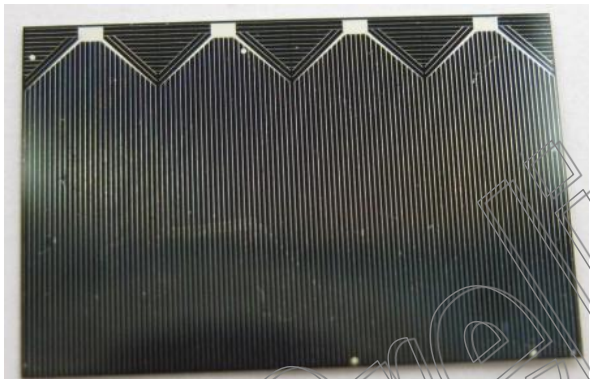
### Metallization

Silver metallization on front busbar and grid fingers  
Silver metallization with 500Å gold on back surface

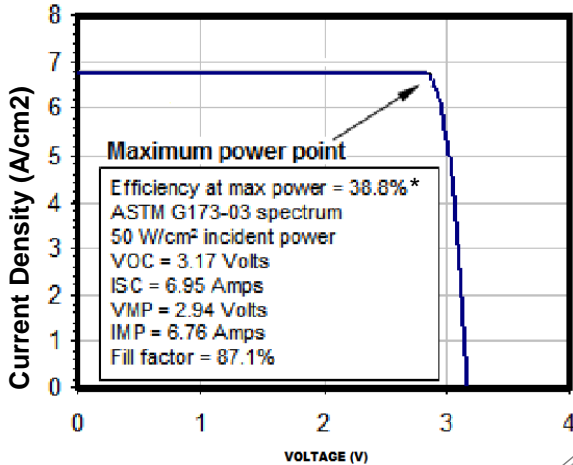
### Qualification Tests Completed

Test	Test Conditions	Qty	Requirement
<b>Performance Tests</b>			
LIV	50 W/cm <sup>2</sup> under ASTM 173G	100%	Avg $\eta_{mp} > 38.5\%$ ; Min $\eta_{mp} > 36.2\%$
Temp Intensity	50, 75 & 100 W/cm <sup>2</sup> , ASTM 173G at 10°C, 25°C, 65°C, and 110°C	20	Characterization
Weld Degradation	LIV test before and after weld	100% of scribed parts	$NP_{mp} > 0.98$
Spectral Response			Characterization
Angle of incidence	X25 or SR illumination source	10	Characterization
Solar Absorbance	Measure reflectance	10	Characterization
<b>Accelerated Life Tests</b>			
Damp Heat	85C, 85% RH for 2000 hours	30	$NP_{mp} > 0.9$
Thermal Cycle	IEEE 1513 (500 cycles -40°C to +110°C)	25	$NP_{mp} > 0.9$
High Temp Soak in Nitrogen	unbiased soak at 200°C and 250°C in Nitrogen	15 at each T	$NP_{mp} > 0.95$ after 25 yrs

\* Full Qualification Report Is Available Upon Request

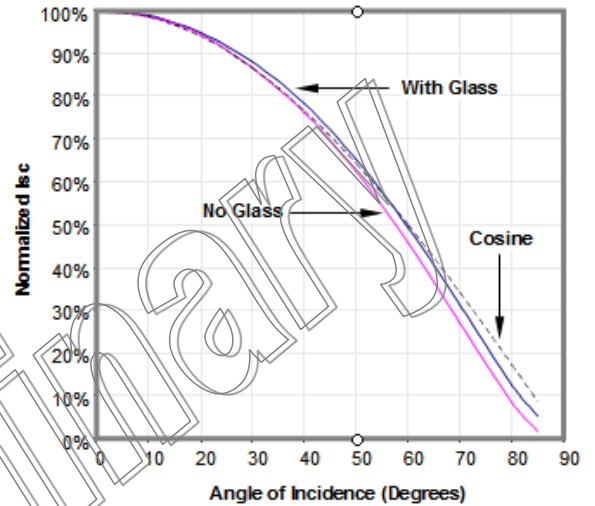


## Typical Current-Voltage Characteristics

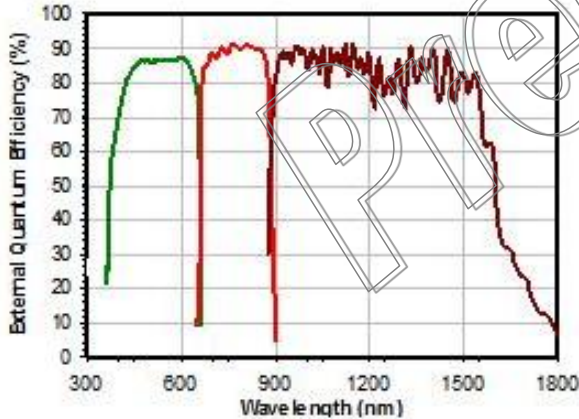


\* Aperture area efficiency (excluding weld pads and inactive edges)

## Response Versus Angle of Incidence



## Spectral Response



## Typical Population Efficiency Distribution (Total Area Efficiency)

